













- ► Ceramic High Power
- ➤ 2016 0.78t Series
- ➤ SWIR (1000~1100nm)

N0F62S41



# **2016 0.78t Series**





#### **FEATURES:**

Package: Ceramic IR CHIP SMT Package

Forward Current: 100mA Forward Voltage (typ.): 1.3V

Radiant Power (typ.): 6mW@100mA Colour: Short Wavelength Infrared (SWIR)

Peak Wavelength: 1000-1100nm

Viewing angle: 120°

**Materials:** 

L/F: Ceramic

Operating Temperature: -20~+65°C Storage Temperature: -20~+65°C

**Grouping parameters:** 

Forward Voltage

**Radiant Power** 

Peak Wavelength

Soldering methods: IR Reflow soldering

MSL: Level 3 according to J-STD020

Packing: 8mm tape with max.1000pcs/reel, ø178mm (7")

2016 0.78t Series

#### **APPLICATIONS:**

- Security Camera
- Medical Device
- Fluorochemistry **Bacterial Identification**
- Cosmetology
- Magnetic Particle Inspection
- Clean Room Inspection
- Mineralogy



### **CHARACTERISTICS:**

# Absolute Maximum Characteristics (Ta=25°C)

Parameter	Symbol	Ratings	Unit
DC Forward Current	l <sub>F</sub>	100	mA
Reverse Voltage	V <sub>R</sub>	5	V
Leakage Current @5V	I <sub>R</sub>	10	μΑ
Junction Temperature	Tj	125	°C
Thermal Resistance Junction to Solder Point	$R_{thj-sp}$	292	°C/W
Operating Temperature	T <sub>OPR</sub>	-20~+65	°C
Storage Temperature	T <sub>STG</sub>	-20~+65	°C

### Electrical & Optical Characteristics (Ta=25°C)

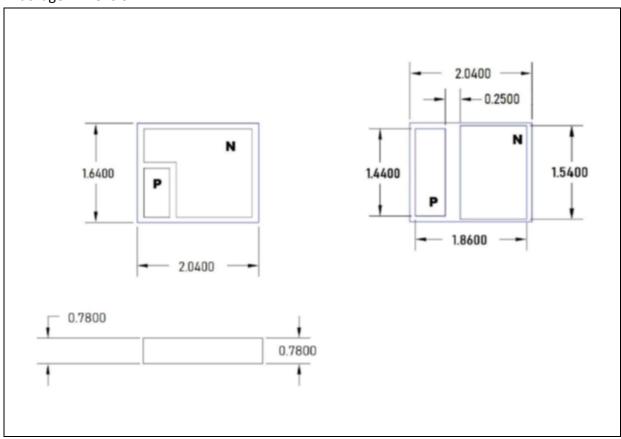
Parameter Symbol		Values			Unit	Test
Parameter	Syllibol	Min.	Тур.	Max.	Offic	Condition
Forward Voltage	V <sub>F</sub>	0.9		1.6	V	I <sub>F</sub> =100mA
Radiant Power	Po	4		8	mW	I <sub>F</sub> =100mA
Peak Wavelength	W <sub>P</sub>	1000		1100	nm	I <sub>F</sub> =100mA
Viewing Angle	2θ <sub>1/2</sub>		120		deg	I <sub>F</sub> =100mA

<sup>1.</sup> Radiant Power (P0)  $\pm 10\%$ , Forward Voltage (VF)  $\pm 0.05$ V, Wavelength (nm)  $\pm 2$ nm



### **OUTLINE DIMENSION:**

### Package Dimension:



- 1. All dimensions are in millimetre (mm).
- 2. Tolerance ±0.13mm, unless otherwise noted.



### **BINNING GROUPS:**

# Forward Voltage Classifications (I<sub>F</sub> = 100mA):

Code	Min.	Max.	Unit
V1	0.9	1.6	V

### Radiant Power Classifications (I<sub>F</sub> = 100mA):

Code	Min.	Max.	Unit
H1	4	8	mW

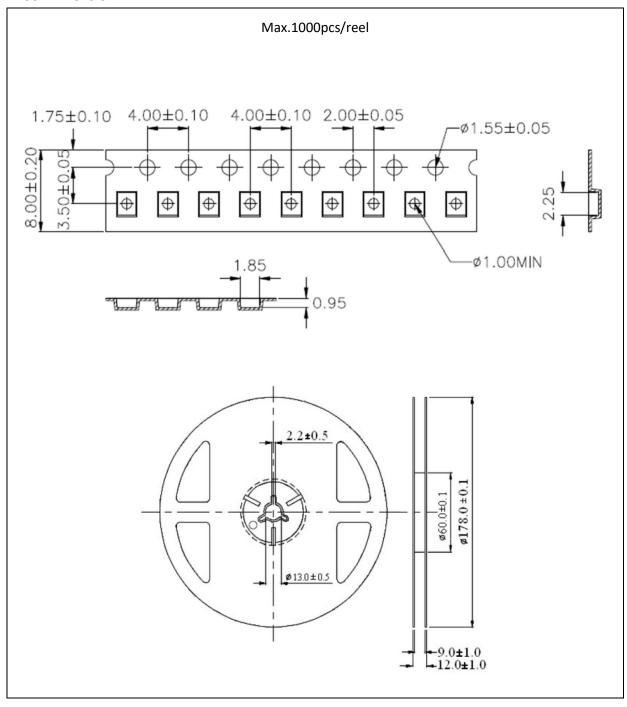
### Peak Wavelength Classifications (I<sub>F</sub> = 100mA):

Code	Min.	Max.	Unit
IR1000	1000	1100	nm



### **PACKING SPECIFICATION:**

#### Reel Dimension:





#### **PRECAUTIONS OF USE:**

#### Storage:

It is recommended to store the products in the following conditions:

- Humidity: 60% R.H. Max.
- Temperature: 5°C~30°C (41°F ~86°F).

Shelf life in sealed bag: 12 months at 5°C~30°C and <60% R.H.

Once the package is opened, the products should be used within a week. Otherwise, they should be kept in a damp-proof box with descanting agent <10% R.H. and apply baking before use.

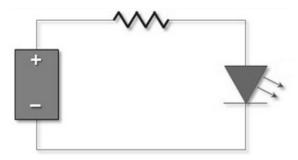
#### Baking:

It is recommended to bake the LED before soldering if the pack has been unsealed for longer than 24hrs. The suggested baking conditions are as followings:

• 65±3°C x 24hrs and <5%RH, taped / reel package.

It's normal to see slight color fading of carrier (light yellow) after baking in process.

### **Testing Circuit:**



Must apply resistor(s) for protection (over current proof).

#### Cleaning:

Use alcohol-based cleaning solvents such as isopropyl alcohol to clean the LED carrier / package. Avoid putting any stress force directly on to the LED lens.

### ESD (Electrostatic Discharge):

Static Electricity or power surge will damage the LED. Use of a conductive wrist band or anti-electrosatic glove is recommended when handing the LED all time. All devices, equipment, machinery, work tables, and storage racks must be properly grounded.

In the events of manual working in process, make sure the devices are well protected from ESD at any time.



# **REVISION RECORD:**

Version	Date	Summary of Revision
A1.0	08/09/2022	Datasheet set-up.